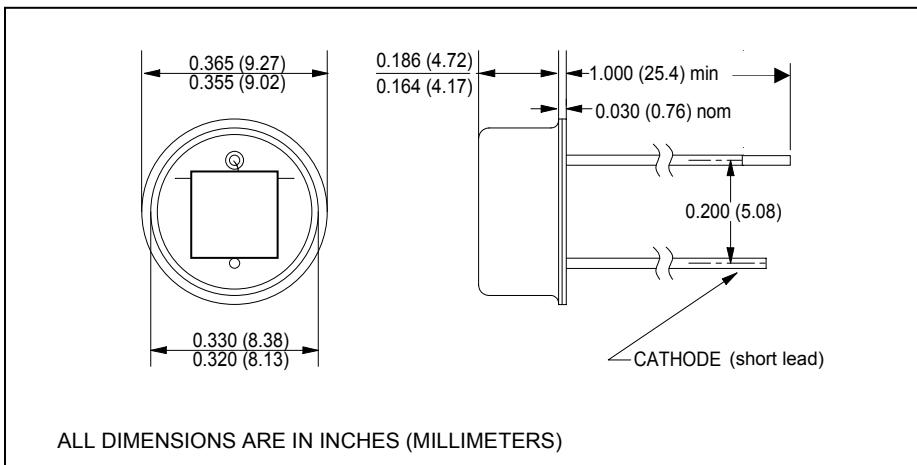


CLD160

Silicon Planar photodiode



July, 2001



features

- 100° acceptance angle
- 860nm peak response
- hermetically sealed TO-5 package
- large photosensitive area
- usable for visible through near-IR

description

The CLD160 is a 0.125" x 0.125" active area silicon photodiode mounted in a flat lensed TO-5 package. Wide acceptance angle permits use in IR air communications ambient light detection, safety and monitoring, security systems, etc. For additional information, call Clairex.

absolute maximum ratings ($T_A = 25^\circ\text{C}$ unless otherwise stated)

storage temperature.....	-35°C to +150°C
operating temperature.....	-35°C to +150°C
lead soldering temperature ⁽¹⁾	260°C
reverse voltage	30V
maximum continuous power dissipation ⁽²⁾	250mW

notes:

1. 0.06" (1.5mm) from the header for 5 seconds maximum.
2. Derate linearly 1.60mW/°C free air temperature to $T_A = +150^\circ\text{C}$.

electrical characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

symbol	parameter	min	typ	max	units	test conditions
I_{SC}	Short-circuit current ⁽³⁾	50.0	70.0	-	μA	$V_{BIAS}=0\text{V}$, $E_e=5\text{mW/cm}^2$
I_D	Dark current	-	-	100	nA	$V_R = 10\text{V}$, $E_e = 0$
V_{BR}	Reverse breakdown	25	-	-	V	$I_R = 100\mu\text{A}$
C_J	Junction capacitance ⁽⁴⁾	-	-	200	pF	
t_r , t_f	Output rise and fall time ⁽⁵⁾	-	-	12	μs	$R_L = 1\text{k}\Omega$
Θ_{HP}	Total angle at half sensitivity points	-	100	-	deg.	

- notes: 3. Light source is a frosted incandescent lamp with color temperature of 2854K.
4. Measured at zero bias, $f = 1\text{MHz}$.
5. Light source is an AlGaAs IRED operating at a peak emission wavelength of 880nm and $E_e = 20\text{mW/cm}^2$.